NSN 5961-01-361-2709

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View Online at https://aerobasegroup.com/nsn/5961-01-361-2709 **Inclosure Material:** Metal **Overall Length:** Between 1.092 inches and 1.131 inches **Overall Height:** 0.610 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-213aa **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 drain to gate voltage and 200.0 drain to source voltage **Current Rating Per Characteristic:** 13.00 amperes source cutoff current of standard range **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 81349-mil-s-19500/569 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: